

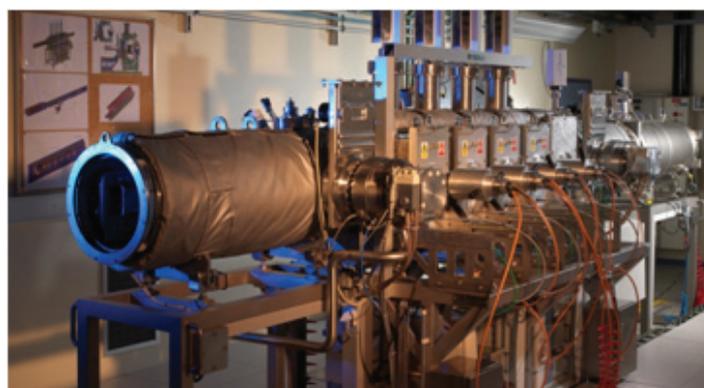
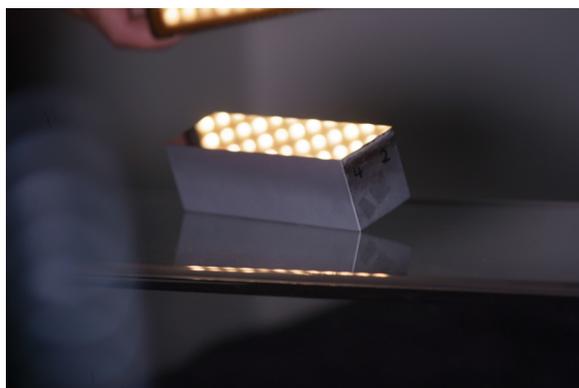
Multilayers

The ESRF Multilayer Facility has developed a strong expertise in the use of multilayers as X-ray optical elements. Today, they are deployed on a considerable number of ESRF beamlines, mainly as focusing devices and monochromators. The key assets of these devices are the following:

- ◆ High reflectivity and large bandwidth
- ◆ Wide photon energy range
- ◆ Large dimensions

Manufacturing process

Multilayers (MLs) are produced by sputter deposition in a gas discharge. Particles ejected from a target form thin layers on a substrate that is moved in front of it. Both uniform or graded layer thicknesses can be generated. ML stacks with d-spacings as low as 2 nm and hundreds of periods can be manufactured.

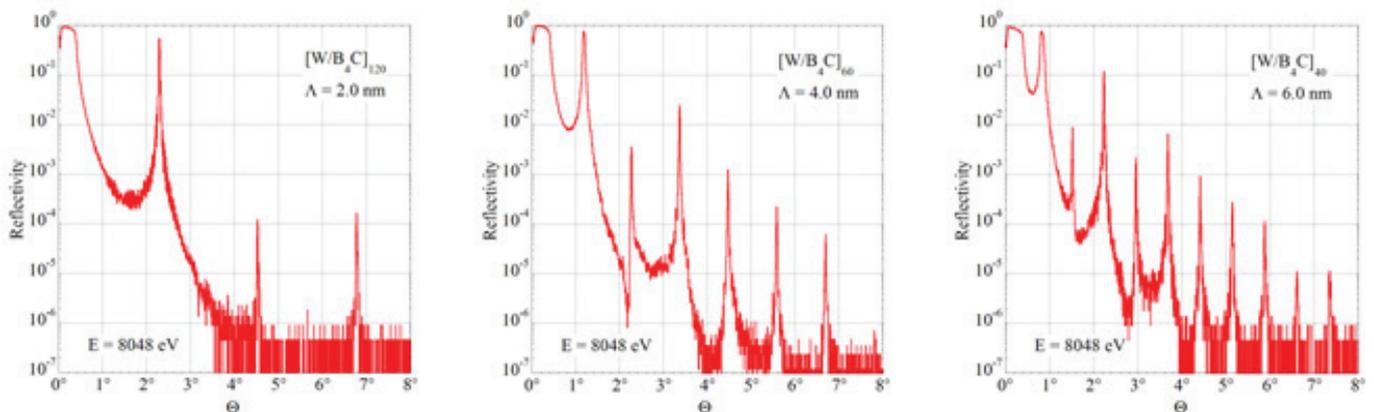


Characteristics

<i>Peak reflectivity</i>	<i>Bandwidth</i>	<i>Photon energy</i>	<i>Maximum dimensions</i>
50 to 90%	1 to 10%	5 to 100 keV	1000mm(L) x 150mm(W) x 100mm(H)

Experimental results

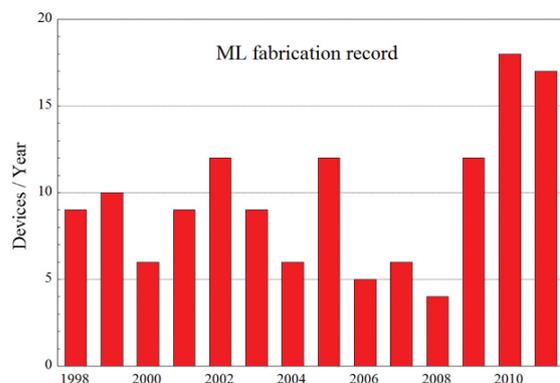
X-ray reflectivity of W/B₄C MLs – example of a “popular workhorse” on many ESRF beamlines



X-ray reflectivity data at $E = 8048 \text{ eV}$ of W/B₄C MLs with d-spacings of $\Lambda = 2.0, 4.0,$ and 6.0 nm . High reflectivity and visibility of higher reflection orders indicate ordered stacking and sharp interfaces.

Our expertise in X-ray multilayer optics

The ESRF X-ray Optics Group can provide expertise in the design, the manufacture and the characterisation of multilayer devices. The ESRF Multilayer Laboratory has developed a robust and precise coating facility [1] that has produced almost 150 devices since 1998. It has contributed to the successful implementation of KB focusing optics with sub-60nm resolution and a photon flux of 10^{12} ph/s [2]. The majority of ESRF beamlines are equipped with multilayer-based optical devices.



Publications

[1]: The new ESRF multilayer facility: progress and perspectives, AIP Conf. Proc. 1234 (2010) 720-723

[2]: Dynamically figured mirror system for high-energy nanofocusing at the ESRF, Proc. SPIE 8139-04 (2011)